

N-channel 100 V, 24.5 mOhm, standard level MOSFET in LFPAK56D using TrenchMOS technology 26 September 2022 Product data sheet

1. General description

Dual standard level N-channel MOSFET in an LFPAK56D (Dual Power-SO8) package using TrenchMOS technology.

2. Features and benefits

- High peak drain current I_{DM}
- Copper clip and flexible Leads
- High operating junction temperature T_i = 175 °C
- Superior reliability
- Low body diode reverse recovery charge Q_r

3. Applications

- Synchronous rectifier
- Forward and flyback converter
- Industrial drive
- Power management system
- Uninterruptible Power Supply (UPS)

4. Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
V _{DS}	drain-source voltage	25 °C ≤ T _j ≤ 175 °C		-	-	100	V
ID	drain current	V _{GS} = 10 V; T _{mb} = 25 °C; <u>Fig. 2</u>		-	-	29.5	А
P _{tot}	total power dissipation	T _{mb} = 25 °C; <u>Fig. 1</u>		-	-	68	W
Tj	junction temperature			-55	-	175	°C
Static charac	teristics FET1 and FET2						
R _{DSon}	drain-source on-state resistance	V _{GS} = 10 V; I _D = 10 A; T _j = 25 °C; Fig. 11		-	19.5	24.5	mΩ
		V _{GS} = 10 V; I _D = 10 A; T _j = 175 °C; Fig. 11; Fig. 12		-	54	68	mΩ
Dynamic cha	racteristics FET1 and FE	T2					
Q _{GD}	gate-drain charge	I _D = 5 A; V _{DS} = 80 V; V _{GS} = 10 V;		-	13.1	-	nC
Q _{G(tot)}	total gate charge	T _j = 25 °C; <u>Fig. 13;</u> <u>Fig. 14</u>		-	38.1	-	nC
Avalanche R	uggedness FET1 and FE	r2					
E _{DS(AL)S}	non-repetitive drain- source avalanche energy	$\label{eq:ID} \begin{array}{l} I_D = 29.5 \text{ A}; \ V_{sup} \leq \ 100 \text{ V}; \ R_{GS} = 50 \ \Omega; \\ V_{GS} = 10 \text{ V}; \ T_{j(init)} = 25 \ ^\circ\text{C}; \ unclamped; \\ \hline Fig. \ 4 \end{array}$	[1] [2]	-	-	83	mJ

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Symbol	Parameter	Conditions	Min	Тур	Мах	Unit
Source-drain d	iode FET1 and FET2					
Qr		$\begin{split} I_{S} &= 5 \text{ A}; \text{ d}I_{S}/\text{d}t = -100 \text{ A}/\mu\text{s}; \text{ V}_{GS} = 0 \text{ V}; \\ \text{V}_{DS} &= 50 \text{ V}; \text{ T}_{j} = 25 ^{\circ}\text{C} \end{split}$	-	62.2	-	nC

[1] Refer to application note AN10273 for further information

[2] Single-pulse avalanche rating limited by maximum junction temperature of 175 °C

5. Pinning information

Table 2	able 2. Pinning information								
Pin	Symbol	Description	Simplified outline	Graphic symbol					
1	S1	source1	8 7 6 5						
2	G1	gate1		D1 D1 D2 D2					
3	S2	source2							
4	G2	gate2							
5	D2	drain2							
6	D2	drain2							
7	D1	drain1		S1 G1 S2 G2					
8	D1	drain1	LFPAK56D; Dual LFPAK (SOT1205)	mbk725					

6. Ordering information

Table 3. Ordering information

Type number	Package				
	Name	Description	Version		
PSMN025-100HS	LFPAK56D; Dual LFPAK	plastic, single ended surface mounted package (LFPAK56D); 8 leads	SOT1205		

7. Marking

Table 4. Marking codes	
Type number	Marking code
PSMN025-100HS	25RS10H

8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V _{DS}	drain-source voltage	25 °C ≤ T _j ≤ 175 °C	-	100	V
V _{DGR}	drain-gate voltage	R _{GS} = 20 kΩ	-	100	V
V _{GS}	gate-source voltage	DC; T _j ≤ 175 °C	-20	20	V
P _{tot}	total power dissipation	T _{mb} = 25 °C; <u>Fig. 1</u>	-	68	W
ID	drain current	V _{GS} = 10 V; T _{mb} = 25 °C; <u>Fig. 2</u>	-	29.5	А
		V _{GS} = 10 V; T _{mb} = 100 °C; <u>Fig. 2</u>	-	22	А

003aak061

150 175 T_{mb} (°C)

200

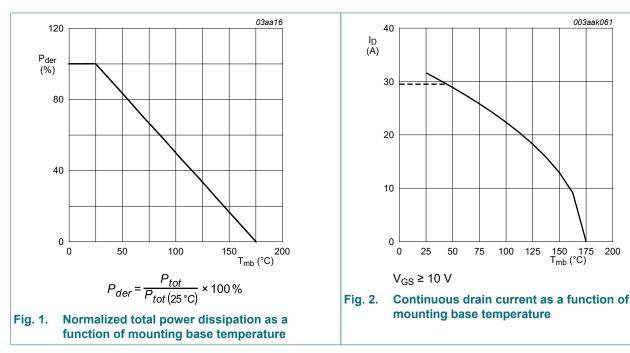
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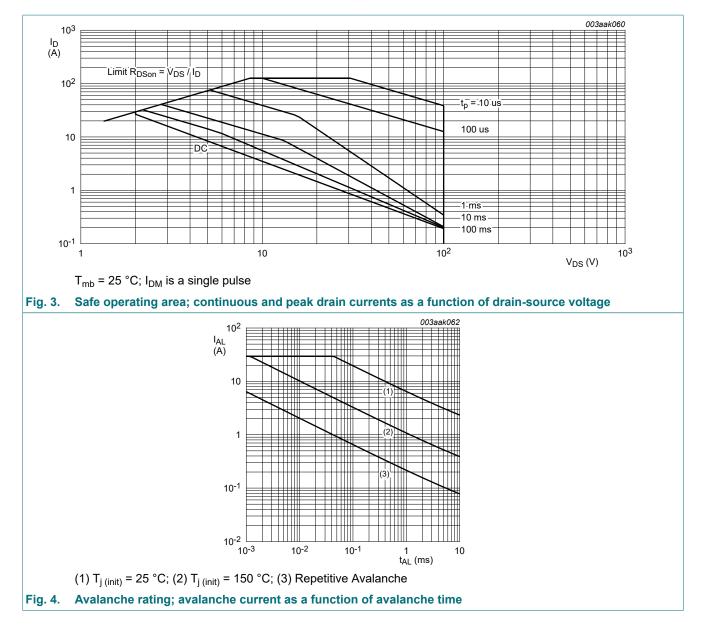
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Symbol	Parameter	Conditions		Min	Max	Unit
I _{DM}	peak drain current	pulsed; $t_p \le 10 \ \mu s$; $T_{mb} = 25 \ ^{\circ}C$; Fig. 3		-	126	A
T _{stg}	storage temperature			-55	175	°C
Tj	junction temperature			-55	175	°C
T _{sld(M)}	peak soldering temperature			-	260	°C
Source-drain	diode FET1 and FET2					
I _S	source current	T _{mb} = 25 °C		-	29.5	А
I _{SM}	peak source current	pulsed; $t_p \le 10 \ \mu s$; $T_{mb} = 25 \ ^{\circ}C$		-	126	A
Avalanche Ru	uggedness FET1 and FET2					
E _{DS(AL)S}	non-repetitive drain- source avalanche energy	$ \begin{array}{l} I_{D} = 29.5 \text{ A}; \ V_{sup} \leq \ 100 \text{ V}; \ R_{GS} = 50 \ \Omega; \\ V_{GS} = 10 \text{ V}; \ T_{j(init)} = 25 \ ^{\circ}\text{C}; \ unclamped; \\ \hline Fig. \ 4 \end{array} $	[1] [2]	-	83	mJ

Refer to application note AN10273 for further information [1]

[2] Single-pulse avalanche rating limited by maximum junction temperature of 175 °C



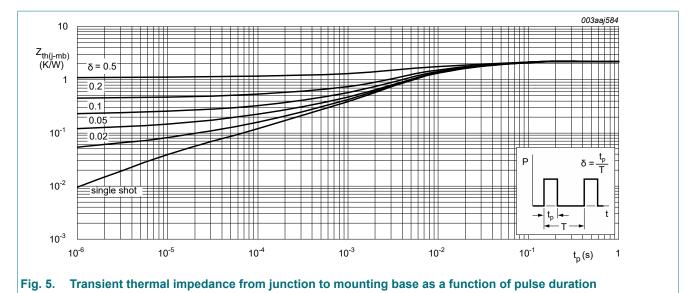


9. Thermal characteristics

Table 6. Thermal characteristics

Symbol	Parameter	Conditions	Min	Тур	Мах	Unit
R _{th(j-mb)}	thermal resistance from junction to mounting base	<u>Fig. 5</u>	-	-	2.21	K/W
R _{th(j-a)}		Minimum footprint; mounted on a printed circuit board	-	95	-	K/W

PSMN025-100HS

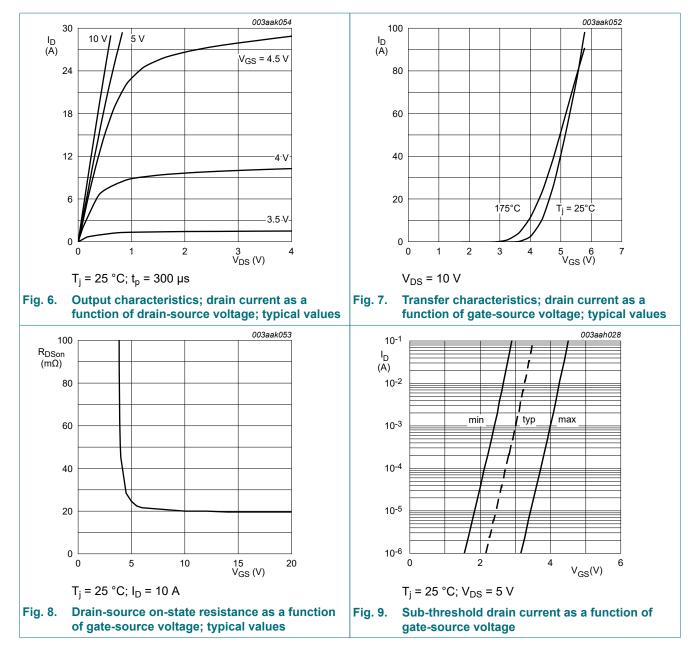


10. Characteristics

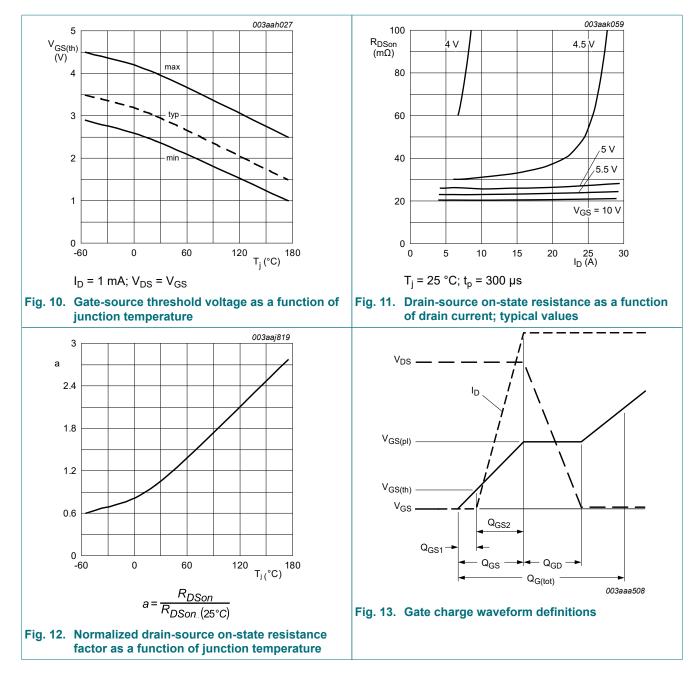
Symbol	Parameter	Conditions	Min	Тур	Мах	Unit
Static chara	cteristics FET1 and FET2					
V _{(BR)DSS}	drain-source	I _D = 250 μA; V _{GS} = 0 V; T _j = -55 °C	90	-	-	V
	breakdown voltage	I _D = 250 μA; V _{GS} = 0 V; T _j = 25 °C	100	-	-	V
V _{GS(th)}	gate-source threshold voltage	$I_D = 1 \text{ mA}; V_{DS} = V_{GS}; T_j = 25 \text{ °C}; Fig. 9;$ Fig. 10	2.4	3	4	V
		$I_D = 1 \text{ mA; } V_{DS} = V_{GS}; T_j = 175 \text{ °C;}$ Fig. 10	1	-	-	V
		I _D = 1 mA; V _{DS} =V _{GS} ; T _j = -55 °C; <u>Fig. 10</u>	-	-	4.5	V
I _{DSS} drain leakage currer	drain leakage current	V _{DS} = 100 V; V _{GS} = 0 V; T _j = 25 °C	-	0.02	1	μA
		V _{DS} = 100 V; V _{GS} = 0 V; T _j = 175 °C	-	-	500	μA
I _{GSS}	GSS gate leakage current	V _{GS} = -20 V; V _{DS} = 0 V; T _j = 25 °C	-	2	100	nA
		V _{GS} = 20 V; V _{DS} = 0 V; T _j = 25 °C	-	2	100	nA
R _{DSon}	drain-source on-state resistance	V _{GS} = 10 V; I _D = 10 A; T _j = 25 °C; Fig. 11	-	19.5	24.5	mΩ
		V _{GS} = 10 V; I _D = 10 A; T _j = 175 °C; Fig. 11; Fig. 12	-	54	68	mΩ
Dynamic ch	aracteristics FET1 and FE	T2	I			
Q _{G(tot)}	total gate charge	I _D = 5 A; V _{DS} = 80 V; V _{GS} = 10 V;	-	38.1	-	nC
Q _{GS}	gate-source charge	T _j = 25 °C; <u>Fig. 13; Fig. 14</u>	-	5.7	-	nC
Q _{GD}	gate-drain charge		-	13.1	-	nC
C _{iss}	input capacitance	V _{DS} = 25 V; V _{GS} = 0 V; f = 1 MHz;	-	1827	2436	pF
C _{oss}	output capacitance	T _j = 25 °C; <u>Fig. 15</u>	-	181	217	pF
C _{rss}	reverse transfer capacitance	1	-	128	175	pF
t _{d(on)}	turn-on delay time	V_{DS} = 80 V; R _L = 15 Ω; V _{GS} = 10 V;	-	8	-	ns
t _r	rise time	$R_{G(ext)} = 5 \Omega; T_j = 25 °C$	-	13.3	-	ns
t _{d(off)}	turn-off delay time	1	-	28.3	-	ns

PSMN025-100HS

Symbol	Parameter	Conditions		Min	Тур	Max	Unit		
t _f	fall time			-	18	-	ns		
Source-drai	Source-drain diode FET1 and FET2								
V _{SD}	source-drain voltage	I _S = 10 A; V _{GS} = 0 V; T _j = 25 °C; <u>Fig. 16</u>		-	0.78	1.2	V		
t _{rr}	reverse recovery time	$I_{S} = 5 \text{ A}; \text{ d}I_{S}/\text{d}t = -100 \text{ A}/\mu\text{s}; \text{ V}_{GS} = 0 \text{ V};$		-	38.4	-	ns		
Q _r	recovered charge	V _{DS} = 50 V; T _j = 25 °C		-	62.2	-	nC		

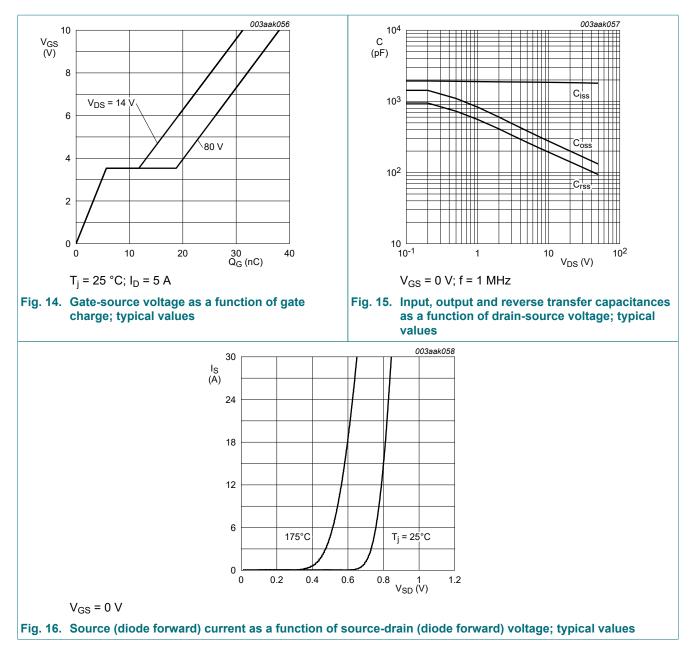


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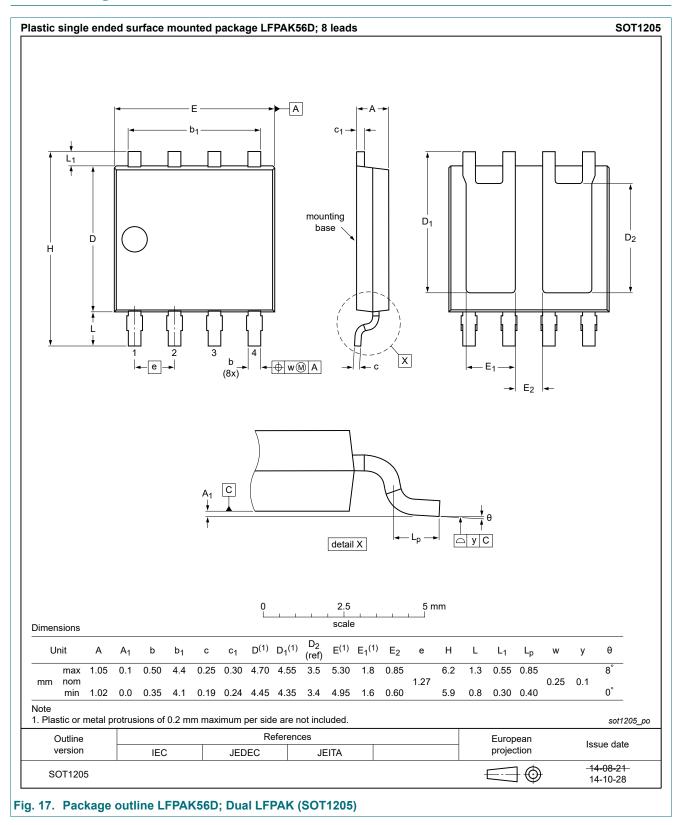


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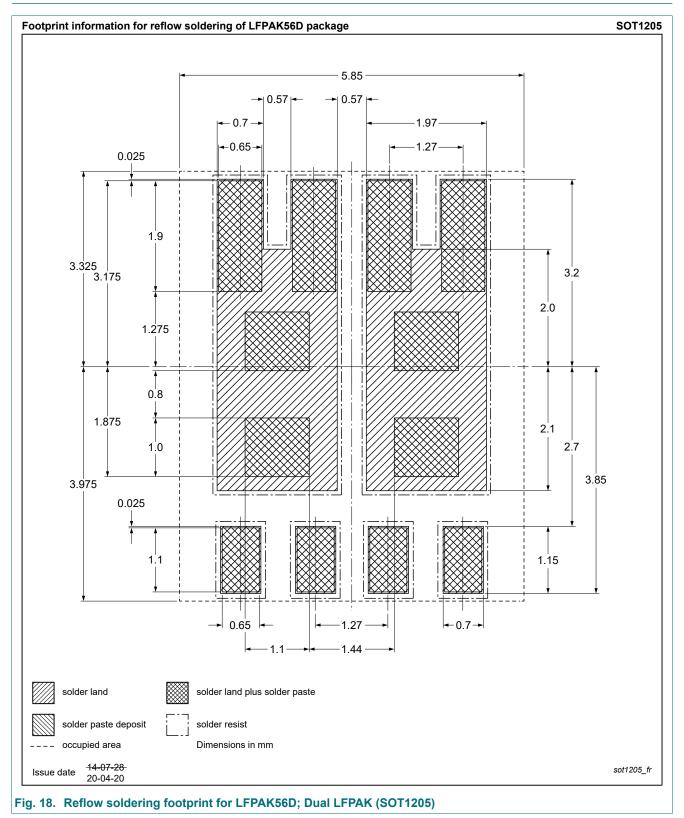
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11. Package outline



12. Soldering



13. Legal information

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Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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